Patent Attorney's Docket No. H1484



IN THE UNITED STATES PATENT AND TRADEMARK OFFICE

In re Paten	ent Application of						
Shibly S. A	Ahmed et al.) Group Art Unit: 2815						
Applicatio	on No.: 10/614,001) Examiner: J. Fenty						
Filed: July	ly 8, 2003						
GA DE	ELECTIVE SILICIDATION OF) ATES IN SEMICONDUCTOR) EVICES TO ACHIEVE) IULTIPLE THRESHOLD VOLTAGES)						
AMENDMENT/REPLY TRANSMITTAL LETTER							
2011 South Customer Crystal Pla	ent and Trademark Office of the Clark Place of Window, Mail Stop Amendment of the Island Two, Lobby, Room 1B03 of the Virginia 22202						
Sir:							
En	nclosed is a reply for the above-identified patent application.						
	A Petition for Extension of Time is also enclosed.						
	A Terminal Disclaimer and a check for \$\sum \$55.00 \$\sum \$110.00\$ to coverequisite Government fee are also enclosed.	r the					
	Applicant(s) request continued examination under 37 C.F.R. § 1.114 and	enclose					
	the \$\Bigcup \$385.00 \Bigcup \$770.00 fee due under 37 C.F.R. \ 1.17(e).						
	Applicant(s) previously submitted , on , for which corexamination is requested.	itinued					
	A request for Entry and Consideration of Submission under 37 C.F.R. § 1 is also enclosed.	.129(a)					

No. of Claims	Highest No. Of Claims Previously Paid For	Extra Claims	Rate	Additional Fee
			x \$18.00 =	
_			x \$ 86.00 =	
adds mul	tiple dependent cla	aims, add \$280	.00	
nent Fee				
status is c	laimed, subtract 5	0% of Total A	mendment Fee	
ITIONAI	L FEE DUE FOR	THIS AMEN	DMENT	
	nent Fee	nent Fee status is claimed, subtract 5	status is claimed, subtract 50% of Total A	adds multiple dependent claims, add \$280.00

To the extent necessary, a petition for an extension of time under 37 C.F.R. § 1.136 is hereby made. Please charge any shortage in fees due in connection with the filing of this paper, including extension of time fees, to Deposit Account No. 50-1070 and please credit any excess fees to such deposit account.

The Commissioner is hereby authorized to charge any other appropriate fees that may be required by this paper that are not accounted for above, and to credit any overpayment, to Deposit Account No. 50-1070.

Respectfully submitted,

HARRITY & SNYDER, L.L.P.

Richard C. Irving Reg. No. 38,499

11240 Waples Mill Road Suite 300 Fairfax, Virginia 22030 (571) 432-0800

Customer Number: 26615

Date: June 18, 2004



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Shibly S. Ahmed) Group Art Unit: 2815
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Application No.: 10/614,001) Examiner: J. Fenty
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Filed: July 8, 2003)
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For: SELECTIVE SILICIDATION OF GATI	ES)
IN SEMICONDUCTOR DEVICES TO)
ACHIEVE MULTIPLE THRESHOLD)
VOLTAGES)

AMENDMENT

U.S. Patent and Trademark Office 220 20th Street S. Customer Window, Mail Stop Amendment Crystal Plaza Two, Lobby, Room 1B03 Arlington, VA 22202

Sir:

In response to the first Office Action, dated March 19, 2004, please amend this application as follows:

Amendments to the Specification begin on page 2 of this paper.

Amendments to the Claims begin on page 3 of this paper.

Remarks begin on page 8 of this paper.